NSN 5961-01-302-7881

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-302-7881 **Inclosure Material:** Ceramic or glass or metal **Overall Length:** 1.900 inches **Terminal Length:** 0.330 inches **Overall Height:** 0.305 inches **Overall Width:** 1.170 inches **Mounting Facility Quantity: Component Name And Quantity:** 2 transistor **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 500.0 drain to gate voltage all transistor and 500.0 drain to source voltage all transistor and 20.0 gate to source voltage all transistor **Current Rating Per Characteristic:** 12.00 amperes drain current all transistor **Power Rating Per Characteristic:** 100.0 watts total device dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Test Data Document:** 04939-717801332 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 6 pin Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

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